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March 2016



FFA40UP35S 40 A, 350 V Ultrafast Diode

Features

- Ultrafast Recovery, t_{rr} < 55 ns (@ I_F = 40 A)
- Max. Forward Voltage, V_F =1.6 V(T_c = 25°C)
- Reverse Voltage: V_{RRM} = 350 V
- · Avalanche Energy Rated
- · RoHS Compliant

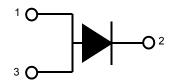
Applications

- · General Purpose
- · SMPS, Free-Wheeling Diode for Motor Application
- · Power Switching Circuits, Welder, UPS

Description

The FFA40UP35S is an ultrafast diode with low forward voltage drop and rugged UIS capability. This device is intended for use as freewheeling and clamping diodes in a variety of switching power supplies and other power switching applications. It is specially suited for use in switching power supplies and industrial applicationa as welder and UPS application.





1. Anode 2. Cathode 3. Anode

Absolute Maximum Ratings T_C = 25°C unless otherwise noted

| Symbol | Parameter | Ratings | Unit | |
|-----------------------------------|---|-------------|------|--|
| V_{RRM} | Peak Repetitive Reverse Voltage | 350 | V | |
| V_{RWM} | Working Peak Reverse Voltage | 350 | V | |
| V_R | DC Blocking Voltage | 350 | V | |
| I _{F(AV)} | Average Rectified Forward Current @ T _C = 125°C | 40 | Α | |
| I _{FSM} | Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave | 300 | А | |
| T _J , T _{STG} | Operating and Storage Temperature Range | -65 to +175 | °C | |

Thermal Characteristics

| Symbol | Parameter | Ratings | Unit |
|-----------------|--|---------|------|
| $R_{\theta JC}$ | Maximum Thermal Resistance, Junction to Case | 0.8 | °C/W |

Package Marking and Ordering Information

| Part Number | Top Mark | Package | Packing Method | Reel Size | Tape Width | Quantity |
|--------------|----------|---------|----------------|-----------|------------|----------|
| FFA40UP35STU | F40UP35S | TO-3P | Tube | N/A | N/A | 30 |

Electrical Characteristics $T_C = 25^{\circ}C$ unless otherwise noted

| Symbol | Parameter | Min. | Тур. | Max. | Unit | |
|---|--|---|------|----------------|------------|----------------|
| V _F 1 | I _F = 40 A I _F = 40 A | $T_{\rm C} = 25^{\rm o}{\rm C}$ $T_{\rm C} = 125^{\rm o}{\rm C}$ | | - | 1.6 1.5 | V |
| I _R 1 | V _R = 350 V V _R = 350 V | $T_{C} = 25^{\circ}C$ $T_{C} = 125^{\circ}C$ | | - | 100 500 | μА |
| t _{rr} | $I_F = 1 \text{ A}, \text{ di}_F/\text{dt} = 100 \text{ A/}\mu\text{s}, \text{ V}_R = 30 \text{ V}$ $I_F = 40 \text{ A}, \text{ di}_F/\text{dt} = 200 \text{ A/}\mu\text{s}, \text{ V}_R = 230 \text{ V}$ | T _C = 25°C | | 26 28 | 53 55 | ns |
| t _a t _b Q _{rr} | $I_F = 40 \text{ A}, \text{ di}_F/\text{dt} = 200 \text{ A/}\mu\text{s}, \text{ V}_R = 230 \text{V}$ | T _C = 25°C | - | 17 11 36 | - | ns ns nC |
| W _{AVL} | Avalanche Energy (L = 40 mH) | 1 | 20 | - | - | mJ |

Notes: 1: Pulse: Test Pulse width = $300\mu s$, Duty Cycle = 2%

Test Circuit and Waveforms

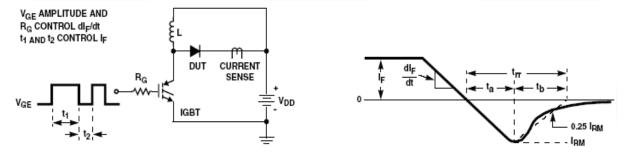


Figure 1. Diode Reverse Recovery Test Circuit & Waveform

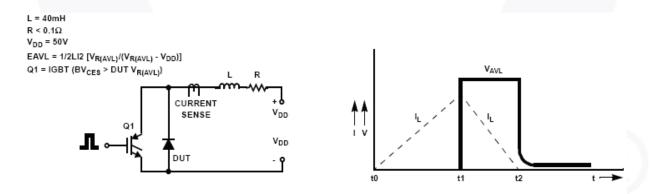


Figure 2. Unclamped Inductive Switching Test Circuit & Waveform

Typical Performance Characteristics

Figure 3. Typical Forward Voltage Drop vs. Forward Current

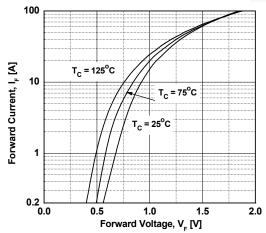


Figure 5. Typical Junction Capacitance

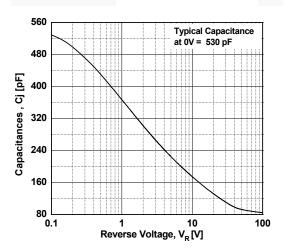


Figure 7. Typical Reverse Recovery Current vs. di_F/dt

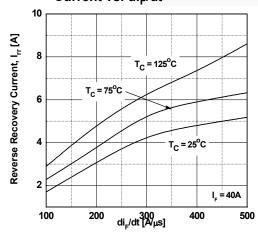


Figure 4. Typical Reverse Current vs.

Reverse Voltage

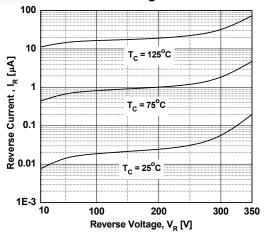


Figure 6. Typical Reverse Recovery Time vs. di_F/dt

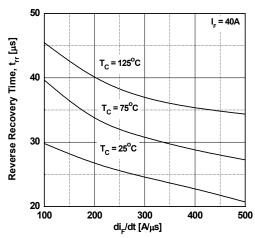
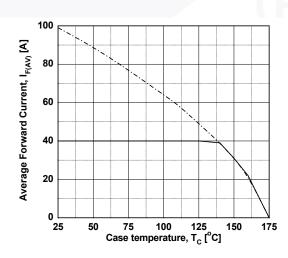
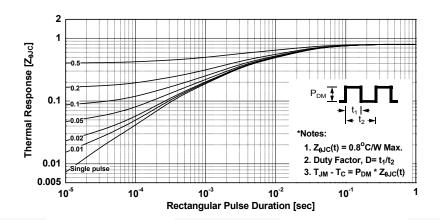


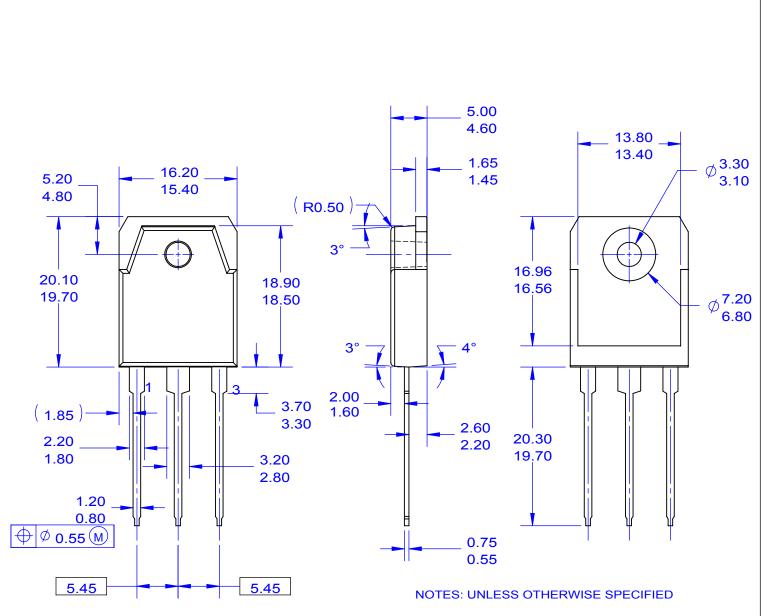
Figure 8. Forward Current Derating Curve

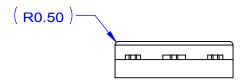


Typical Performance Characteristics (Continued)

Figure 9. Transient Thermal Response Curve







- A) THIS PACKAGE CONFORMS TO EIAJ SC-65 PACKAGING STANDARD.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSION AND TOLERANCING PER ASME14.5-2009.
- D) DIMENSIONS ARE EXCLUSSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSSIONS.
- E) DRAWING FILE NAME: TO3PN03AREV2.
- F) FAIRCHILD SEMICONDUCTOR.



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